

Nano and micro-scale simulations of Si/4H-SiC and Si/3C-SiC NN-heterojunction diodes

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Silicon Carbide and Related Materials 2018 : 12th European Conference on Silicon Carbide and Related Materials (ECSCRM 2018) : Selected, peer reviewed papers from the European Conference on Silicon Carbide and Related Materials (ECSCRM 2018), September 2-6, 2018, Birmingham, UK 2019 / p. 357–361 <https://doi.org/10.4028/www.scientific.net/MSF.963.357> [Conference proceeding at Scopus](#) [Article at Scopus](#)

Non-destructive eddy current measurements for silicon carbide heterostructure analysis

Sahakyan, Armen; Koel, Ants; Rang, Toomas Materials and contact characterisation VIII 2017 / p. 49-60 : ill <http://dx.doi.org/10.2495/MC170061>

Simulations of heterostructures based on 3C-4H and 6H-4H silicon carbide polytypes

Rashid, Muhammad Haroon; Koel, Ants; Rang, Toomas Silicon carbide and related materials 2017 : ICSCRM 2017 : selected, peer reviewed papers from the 2017 International Conference on Silicon Carbide and related materials, September 17-22, 2017, Washington, DC, USA 2018 / p. 302-305 : ill <https://doi.org/10.4028/www.scientific.net/MSF.924.302> [Conference Proceedings at Scopus](#) [Article at Scopus](#)